



1 1			1	cification of l	NHE520F	R-HF	5/7					
bsolute	e Maximu	ım Ratın	igs							(Ta-	=25°C)	
		Iten	n	Symbol	Sympol Do						Unit	
	Max	.Control		Ic max	40°C	curre	Rati	-			mA	
		ating ter		Topr	40 C	curre	in ui		40~+11		°C	
	-	ige temp	-	Tstg					40~+12		ĉ	
		• •		istance, stay v	within inpu	it volt:	age de				C	
	Note.	without it	contention res	istance, stay v	vitini inpe	n von	ige de	iating et		ciope		
Input V	out Voltage Derating Curve						t Curre	nt Derati	ng Curve			
					20	_						
			\mathbb{N}							\mathbb{N}		+++
					Input Current (mA)							
			+++	\mathbb{N}							++	+
					- 010 불							
					5							
					_							
Electric	-20 0 al Charac	20 40 Anbient T	emp. (°C)	100 120 1	」 0 40 -		40 -2	20 0	20 40 Anbient Te			100 12
Hal I	al Charac Item vol tage	Anbient T	emp. (°C) Symbol *VH	C Vc=1V, B=	condition 50mT	-60 -	40 -2	Min 196		emp. (°C	» Max 320	Un m\
Hal I Offse	al Charac Item vol tage	Anbient T	emp. (°C) Symbol	C Vc=1V, B= Vc=1V, B	condition 50mT 3=0mT	-60 -	40 -2	Min	Anbient Te	emp. (°C	Max	Un
Hal I Offse Input	al Charac Item vol tage et voltage t resistanc	Anbient T	symbol *VH Vo	C Vc=1V, B=	condition 50mT B=0mT B=0mT	-60 -	40 -2	Min 196 -7	Anbient Te	emp. (°C	Max 320 +7	Un m\ mV
Hal I Offse Input Outp	Item vol tage et voltage t resistanc ut resistan o.coeff.	Anbient T	symbol *VH Vo Rin	Vc=1V, B= Vc=1V, B Ic=1mA, Ic=1mA,I Average of 20°C base	condition 50mT 3=0mT B=0mT B=0mT on 0~40	-60 -		Min 196 -7 240	Anbient Te	iemp. (°C	Max 320 +7 550	Un m\ m\
Hall Offse Input Outp Temp of VI	Item vol tage et voltage t resistanc ut resistan o.coeff.	Anbient T	symbol *VH Vo Rin Rout	Vc=1V, B= Vc=1V, B Ic=1mA, Ic=1mA,I Average of 20°C base	condition 50mT 3=0mT B=0mT B=0mT bn 0~40 c Lc=5m	-60 -	or	Min 196 -7 240	Anbient To Stand	lard	Max 320 +7 550	Un m\ Ω
Hall Offse Input Outp Temp of VI	Item vol tage et voltage t resistanc ut resistan o.coeff. H	Anbient T	emp. (°C) Symbol *VH Vo Rin Rout αHI	CC Vc=1V, B= Vc=1V, B Ic=1mA, I Ic=1mA, I Average of 20°C base B=50mT	condition 50mT B=0mT B=0mT B=0mT Dn 0~40 C C Lc=5m Dn 0~40	-60	or	Min 196 -7 240	Stand	lard	Max 320 +7 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VI	Item vol tage et voltage t resistanc ut resistan 5.coeff. H	Anbient T	emp. (°C) Symbol *VH Vo Rin Rout αHI	Vc=1V, B= Vc=1V, B Ic=1mA, Ic=1mA,I Average of 20°C base B=50mT Average of	Condition 50mT 3=0mT B=0mT B=0mT bn 0~40 c Ic=5m bn 0~40 c	-60	or	Min 196 -7 240	Stand	lard	Max 320 +7 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VI	Item vol tage et voltage t resistanc ut resistan 5.coeff. H	Anbient T eteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI	Vc=1V, B= Vc=1V, B Ic=1mA, Ic=1mA,I Average of 20°C base B=50mT Average of 20°C base B=0mT	Condition 50mT 3=0mT B=0mT B=0mT bn 0~40 c Ic=5m bn 0~40 c	-60	or or	Min 196 -7 240 240	Anbient To Stand	lard 8	Max 320 +7 550 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VI	Item vol tage et voltage t resistanc ut resistan b.coeff. H	Anbient T eteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI	Vc=1V, B= Vc=1V, B= Ic=1mA, Ic=1mA,I Average of 20°C base B=50mT Average of 20°C base B=0mT	$\frac{140}{50mT}$ $\frac{50mT}{8=0mT}$ $\frac{1}{8=0mT}$ $\frac{1}{9}$	-60 D°C fo A D°C fo nA ured v	or or alue	Min 196 -7 240 240	Anbient To Stand	lard 8	Max 320 +7 550 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VI	Item vol tage et voltage t resistanc ut resistan b.coeff. H	Anbient T eteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI	Vc=1V, B= Vc=1V, B= Ic=1mA, Ic=1mA,I Average of 20°C base B=50mT Average of 20°C base B=0mT	initial initial condition 50mT 50mT 50mT B=0mT B=0mT B=0mT 0~40 initial 0~40 initial 0~40 initial 0~40 initial 0~40 initial 0~40	-60 D°C fo A D°C fo nA ured v	or or alue	Min 196 -7 240 240	Anbient To Stand	lard 8	Max 320 +7 550 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VH Temp of res	Item vol tage et voltage t resistanc ut resistan c.coeff. H c.coeff. sistance *VH=V	Anbient T eteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI βR	C $Vc=1V, B=$ $Vc=1V, B$ $Ic=1mA, I$ $Ic=1mA, I$ $Average of C$ $B=50mT$ $Average of C$ $B=0mT$ VHM Vo	condition 50mT 3=0mT B=0mT B=0mT Dn 0~40 c Ic=5m Dn 0~40 c Ic=0.1m I : Measu $I : Offset$	-60 D°C fo A D°C fo nA ured v volta	or or alue	Min 196 -7 240 240	Anbient To Stand	lard 8	Max 320 +7 550 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VI Temp of res	al Charac Item vol tage et voltage et voltage et voltage tresistanc ut resistanc o.coeff. H o.coeff. sistance *VH=V cation of	Anbient T eteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI βR	C $Vc=1V, B=$ $Vc=1V, B$ $Ic=1mA, I$ $Ic=1mA, I$ $Average of the set of th$	condition 50mT 3=0mT B=0mT B=0mT Dn 0~40 c Ic=5m Dn 0~40 c Ic=0.1m I : Measu $I : Offset$	-60 D°C fo A D°C fo nA ured v volta	or or alue	Min 196 -7 240 240	Anbient To Stand	lard 8	Max 320 +7 550 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VI Temp of res	al Charac Item vol tage et voltage et voltage et voltage tresistanc ut resistanc o.coeff. H o.coeff. sistance *VH=V cation of	Anbient T eteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI βR	C $Vc=1V, B=$ $Vc=1V, B$ $Ic=1mA, I$ $Ic=1mA, I$ $Average of the set of th$	condition 50mT 3=0mT B=0mT B=0mT Dn 0~40 c Ic=5m Dn 0~40 c Ic=0.1m I : Measu $I : Offset$	-60 $-$	or or alue o	Min 196 -7 240 240	Anbient To Stand	emp. (°C	Max 320 +7 550 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VI Temp of res	Item vol tage et voltage t resistanc ut resistan o.coeff. H o.coeff. sistance *VH=V cation of assificatio	Anbient T exteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI βR Hall volta, k for Hall	Vc=1V, B=Vc=1V, BIc=1mA,Ic=1mA,IAverage of $20^{\circ}C$ baseB=50mTAverage of $20^{\circ}C$ baseB=0mTVHMVoge and Printvoltage	condition 50mT 3=0mT B=0mT B=0mT Dn 0~40 c Ic=5m Dn 0~40 c Ic=0.1m I : Measu $I : Offset$	-60 $-$	or or alue of ge	Min 196 -7 240 240 of Hall	Anbient To Stand	emp. (°C	Max 320 +7 550 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VH Temp of res	al Charac Item vol tage et voltage et voltage et voltage t resistance ut resistance D.coeff. H D.coeff. sistance *VH=V cation of assification H(mV)	Anbient T exteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI βR Hall volta, k for Hall of Rank	C $Vc=1V, B=$ $Vc=1V, B$ $Ic=1mA, I$ $Ic=1mA, I$ Average of $20^{\circ}C$ base $B=50mT$ Average of $20^{\circ}C$ base $B=0mT$ VHM Voge and PrintvoltagePrinting	condition 50mT 3=0mT B=0mT B=0mT Dn 0~40 c Ic=5m Dn 0~40 c Ic=0.1m I : Measu $I : Offset$	-60 $-$	or or alue of ge	Min 196 -7 240 240 of Hall tion of HE520F	Anbient To Stand -1.8 -1.8 voltage	emp. (°C	>> Max 320 +7 550 550 0mT ()	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VI Temp of res Classific Classific Classific	Item vol tage et voltage t resistanc ut resistanc o.coeff. H o.coeff. sistance *VH=V cation of assification H(mV) 6~236	Anbient T exteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI βR Hall volta, k for Hall of Rank 5	Vc=1V, B= $Vc=1V, B$ $Ic=1mA, I$ $Ic=1mA, I$ $Average of 20°C baseB=50mTAverage of 20°C baseB=0mTVHMVoge and PrintvoltagePrinting5$	condition 50mT 3=0mT B=0mT B=0mT Dn 0~40 c Ic=5m Dn 0~40 c Ic=0.1m I : Measu $I : Offset$	-60 $-$	or or alue of ge	Min 196 -7 240 240 of Hall tion of HE520F	Anbient To Stand -1.8 -1.8 voltage	emp. (°C	Max 320 +7 550 550	Un m\ Ω Ω %/°
Hall Offse Input Outp Temp of VH Temp of res Classific Cla *VH 196 228	al Charac Item vol tage et voltage et voltage et voltage t resistance ut resistance D.coeff. H D.coeff. sistance *VH=V cation of assification H(mV)	Anbient T exteristics	emp. (°C) Symbol *VH Vo Rin Rout αHI βR Hall volta, k for Hall of Rank	C $Vc=1V, B=$ $Vc=1V, B$ $Ic=1mA, I$ $Ic=1mA, I$ Average of $20^{\circ}C$ base $B=50mT$ Average of $20^{\circ}C$ base $B=0mT$ VHM Voge and PrintvoltagePrinting	condition 50mT 3=0mT B=0mT B=0mT Dn 0~40 c Ic=5m Dn 0~40 c Ic=0.1m I : Measu $I : Offset$	-60 $-$	or or alue o ge	Min 196 -7 240 240 0 f Hall tion of HE520F (□ i	Anbient To Stand -1.8 -1.8 voltage	emp. (°C	>> Max 320 +7 550 550 0mT ()	Un m\ Ω Ω %/°



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C Nicera®

Specification of NHE520FR-HF6/7

4. Guarantee conditions for mounting mini-mould package

(1) Recommended conditions for soldering the product to the substrate

1) Please avoid heating and cooling the main body rapidly.

2) Preheating should be done for $2 \sim 3 \text{ min.}$ at $150 \sim 200 \degree \text{C}$

- 3) Soldering for 5 sec. at $245 \sim 260$ °C is the best condition for soldering (example: reflow).
- (2) Soldering method and guaranteed temperature.

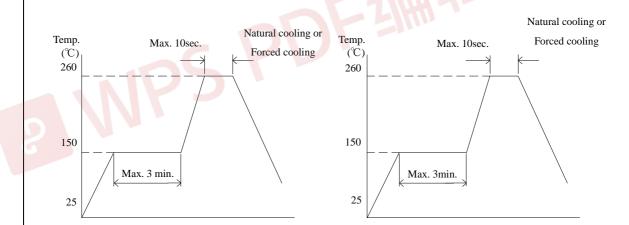
1) Soldering Method

Method	Conditions	Temp.
Reflow	Soldering is done in high temp circumstances	MAX260°C
		10sec.
Solder dip	Soldering is done in the dipping sink for solder.	MAX260°C
		10sec.
Soldering	Repair soldering parts of the lead wire by using	350°℃
Iron	the soldering iron.	within 3sec.

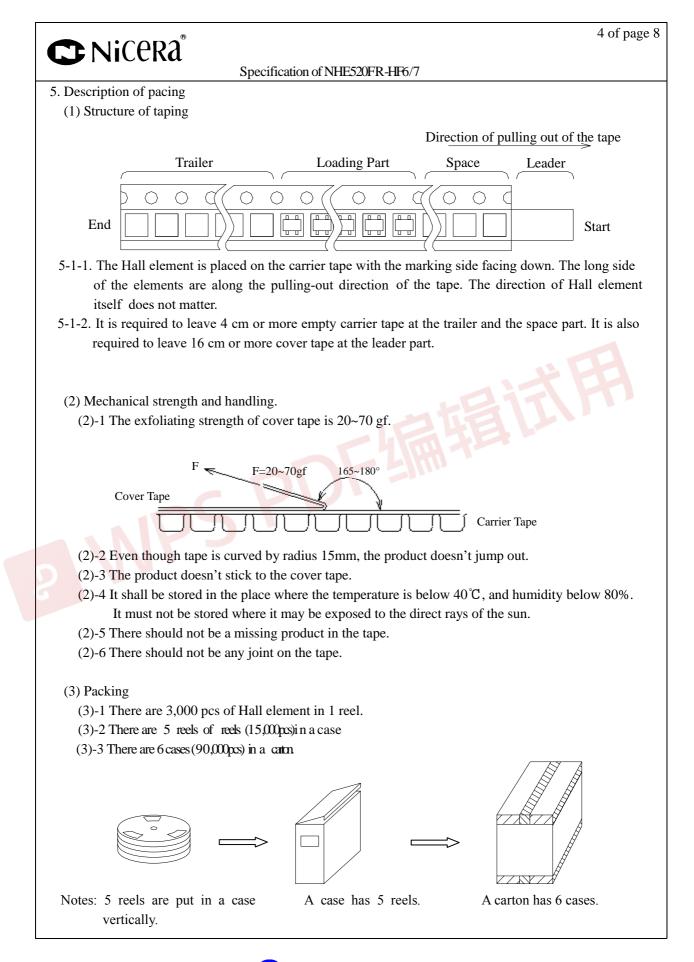
2) Range of guaranteed temp.

Reflow

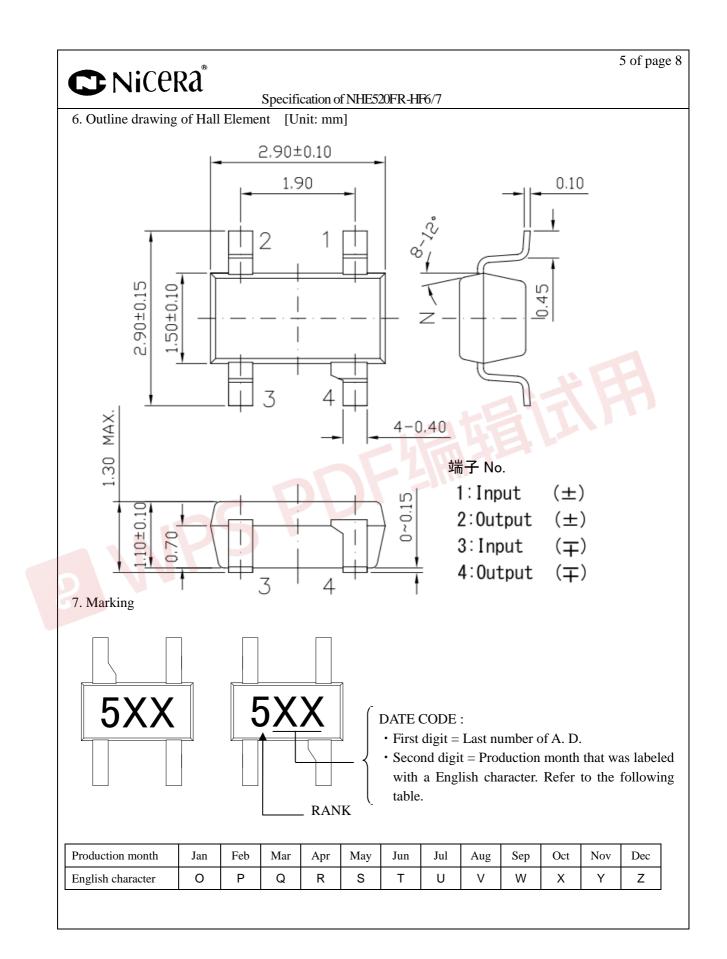
Solder dip



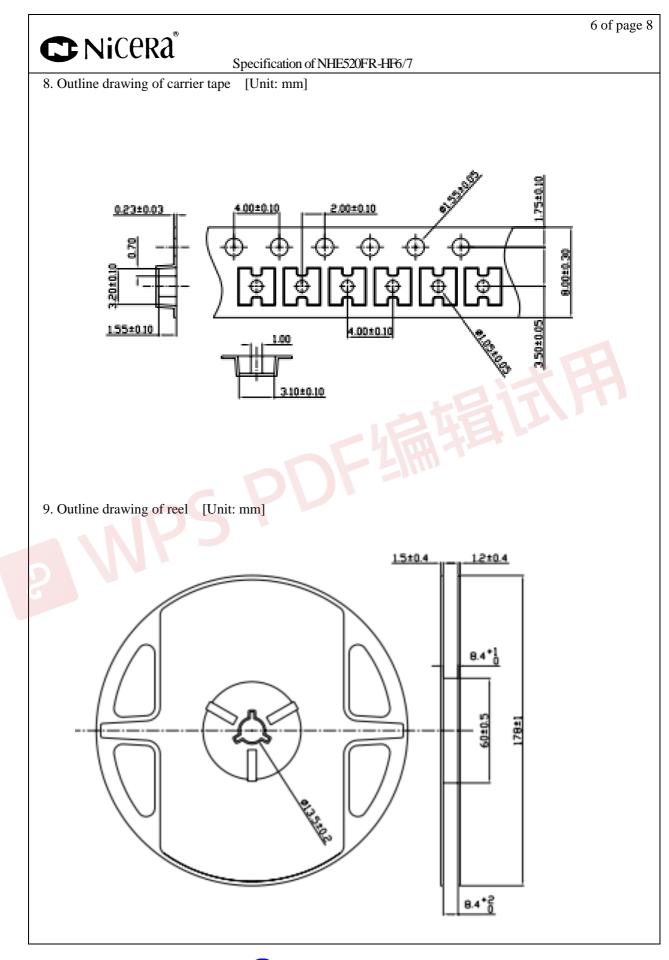




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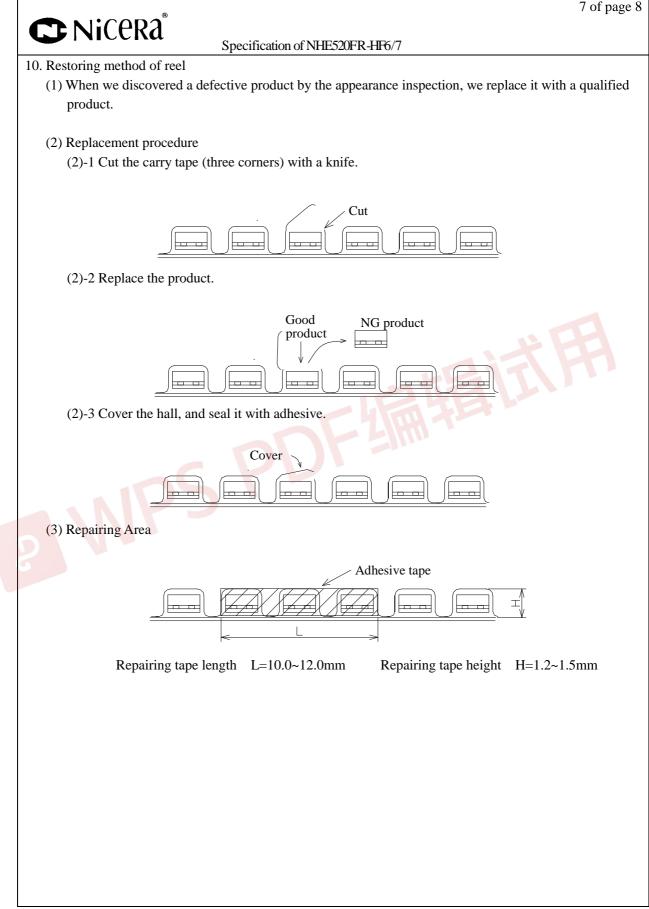






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8 of page 8 C Nicera® Specification of NHE520FR-HF6/7 11. Cautions (1) Attention for storage Because the products are packed in tapes when shipped, it is required to pay most attention on the Circumstances for the storage of the products, as we mention in the section 5. If the products are stored under the following circumstances or equivalent circumstances, damage to appearance, defectiveness of characteristics and assembly deterioration may occur. Please understand the above and store the products with care. Recommended Circumstance is to keep them in N2-Box. a. Circumstances under high temperature, high humidity for long hours. b. Circumstances that has corrosive gas, organic gas, acidity and alkalinity background. c. Dusty Circumstances. (2) Attention for mounting Please follow the matters as we mention in the section 4 (3) Notice This specification certifies the quality of Hall element itself. The guarantee does not cover the following situations. a. When it is inappropriately handled or used in a wrong way by the user. b. When it gets additional treatment by others (except for the supplier). c. When it meets a situation that Nicera is not able to control such as natural disasters etc. The guarantee of this specification limits the guarantee to replacing the Hall element itself. The expenses for exchange and /or the damage caused by the defective or failed products are not covered. Your understanding and cooperation is highly appreciated.

